

# Phase Control Thyristors (Stud Version), 230 A



PRIMARY CHARACTERISTICS				
I <sub>T(AV)</sub>	230 A			
V <sub>DRM</sub> /V <sub>RRM</sub>	400 V, 800 V, 1200 V			
$V_{TM}$	1.55 V			
I <sub>GT</sub>	150 mA			
T <sub>J</sub>	-40 °C to +125 °C			
Package	TO-93 (TO-209AB)			
Circuit configuration	Single SCR			

#### **FEATURES**

- · Center amplifying gate
- International standard case TO-93 (TO-209AB)



- Glass-metal seal up to 1200 V
- Compression bonded encapsulation for heavy duty operations such as severe thermal cycling
- Designed and qualified for industrial level
- Material categorization: for definitions of compliance please see <a href="https://www.vishay.com/doc?99912">www.vishay.com/doc?99912</a>

#### **TYPICAL APPLICATIONS**

- DC motor controls
- Controlled DC power supplies
- AC controllers

MAJOR RATINGS AND CHARACTERISTICS						
PARAMETER	TEST CONDITIONS	VALUES	UNITS			
1		230	A			
$I_{T(AV)}$	T <sub>C</sub>	85	°C			
I <sub>T(RMS)</sub>		360	A			
1	50 Hz	5700	^			
I <sub>TSM</sub>	60 Hz	5970	A			
l <sup>2</sup> t	50 Hz	163	kA <sup>2</sup> s			
	60 Hz	149	KA-S			
V <sub>DRM</sub> /V <sub>RRM</sub>		400 to 1200	V			
t <sub>q</sub>	Typical	100	μs			
T <sub>J</sub>		-40 to 125	°C			

#### **ELECTRICAL SPECIFICATIONS**

VOLTAGE RATINGS								
TYPE NUMBER	VOLTAGE CODE	V <sub>DRM</sub> /V <sub>RRM</sub> , MAXIMUM REPETITIVE PEAK AND OFF-STATE VOLTAGE V	V <sub>RSM</sub> , MAXIMUM NON-REPETITIVE PEAK VOLTAGE V	$\begin{split} I_{DRM}/I_{RRM} & \text{MAXIMUM AT} \\ T_J &= T_J & \text{MAXIMUM} \\ & \text{mA} \end{split}$				
	04	400	500					
VS-ST230S	08	800	900	30				
	12	1200	1300					



ABSOLUTE MAXIMUM RATINGS						
PARAMETER	SYMBOL		TEST CONDITIONS			UNITS
Maximum average on-state current	I <sub>T(AV)</sub>	180° conduction, half sine wave		230	Α	
at case temperature	-1(///				85	°C
Maximum RMS on-state current	$I_{T(RMS)}$	DC at 78 °C	case temperat	ure	360	
		t = 10 ms	No voltage		5700	
Maximum peak, one-cycle		t = 8.3 ms	reapplied		5970	Α
non-repetitive surge current	I <sub>TSM</sub>	t = 10 ms	100 % V <sub>RRM</sub>		4800	
		t = 8.3 ms	reapplied	Sinusoidal half wave,	5000	
Maximum I <sup>2</sup> t for fusing		t = 10 ms	No voltage	initial $T_J = T_J$ maximum	163	
	l <sup>2</sup> t	t = 8.3 ms	reapplied	_	148	kA <sup>2</sup> s
		t = 10 ms	100 % V <sub>RRM</sub>		115	
		t = 8.3 ms	reapplied		105	
Maximum I <sup>2</sup> √t for fusing	I <sup>2</sup> √t	t = 0.1 to 10 ms, no voltage reapplied		1630	kA²√s	
Low level value of threshold voltage	V <sub>T(TO)1</sub>	(16.7 % x $\pi$ x $I_{T(AV)}$ < I < $\pi$ x $I_{T(AV)}$ ), $T_J = T_J$ maximum		$I_{T(AV)}$ , $T_J = T_J$ maximum	0.92	V
High level value of threshold voltage	V <sub>T(TO)2</sub>	$(I > \pi \times I_{T(AV)}), T_J = T_J \text{ maximum}$		0.98	ľ	
Low level value of on-state slope resistance	r <sub>t1</sub>	(16.7 % x $\pi$ x $I_{T(AV)} < I < \pi$ x $I_{T(AV)}$ ), $T_J = T_J$ maximum		0.88	mΩ	
High level value of on-state slope resistance	r <sub>t2</sub>	$(I > \pi \times I_{T(AV)}), T_J = T_J \text{ maximum}$		0.81	11122	
Maximum on-state voltage	$V_{TM}$	$I_{pk} = 720 \text{ A}, T_J = T_J \text{ maximum}, t_p = 10 \text{ ms sine pulse}$		1.55	V	
Maximum holding current	l <sub>Η</sub>	T. = 25 °C	anodo supely 1	2 V resistive lead	600	mA
Maximum (typical) latching current	IL	T <sub>J</sub> = 25 °C, anode supply 12 V resistive load		1000 (300)	IIIA	

SWITCHING						
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS		
Maximum non-repetitive rate of rise of turned-on current	dl/dt	Gate drive 20 V, 20 $\Omega$ , $t_r \le 1~\mu s$ $T_J = T_J$ maximum, anode voltage $\le 80~\%~V_{DRM}$	1000	A/µs		
Typical delay time	t <sub>d</sub>	Gate current 1 A, $d_g/dt = 1 A/\mu s$ $V_d = 0.67 \% V_{DRM}, T_J = 25 °C$	1.0			
Typical turn-off time	t <sub>q</sub>	$I_{TM} = 300 \text{ A, } T_J = T_J \text{ maximum, } dI_F/dt = 20 \text{ A/}\mu\text{s,}$ $V_R = 50 \text{ V, } dV/dt = 20 \text{ V/}\mu\text{s, } \text{gate } 0 \text{ V } 100 \Omega, t_p = 500 \mu\text{s}$	100	μs		

BLOCKING				
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum critical rate of rise of off-state voltage	dV/dt	T <sub>J</sub> = T <sub>J</sub> maximum linear to 80 % rated V <sub>DRM</sub>	500	V/µs
Maximum peak reverse and off-state leakage current	I <sub>RRM</sub> , I <sub>DRM</sub>	$T_J = T_J$ maximum, rated $V_{DRM}/V_{RRM}$ applied	30	mA



TRIGGERING						
DADAMETED	SYMBOL	-	TEST COMPLETIONS		UES	
PARAMETER	SYMBOL	TEST CONDITIONS		TYP.	MAX.	UNITS
Maximum peak gate power	P <sub>GM</sub>	$T_J = T_J$ maximum,	t <sub>p</sub> ≤ 5 ms	10.0		W
Maximum average gate power	P <sub>G(AV)</sub>	$T_J = T_J$ maximum,	f = 50 Hz, d% = 50	2	.0	VV
Maximum peak positive gate current	I <sub>GM</sub>	$T_J = T_J$ maximum,	t <sub>p</sub> ≤ 5 ms	3	.0	Α
Maximum peak positive gate voltage	+V <sub>GM</sub>	$T_J = T_J$ maximum, $t_p \le 5$ ms		20 5.0		V
Maximum peak negative gate voltage	-V <sub>GM</sub>					
DC gate current required to trigger	I <sub>GT</sub>	T <sub>J</sub> = - 40 °C	Maximum required gate trigger/current/voltage are the lowest	180	-	
		T <sub>J</sub> = 25 °C		90	150	mA
		T <sub>J</sub> = 125 °C		40	-	
		T <sub>J</sub> = - 40 °C	value which will trigger all units 12 V anode to cathode applied	2.9	-	
DC gate voltage required to trigger	$V_{GT}$	T <sub>J</sub> = 25 °C	v anoue to cathode applied	1.8	3.0	V
		T <sub>J</sub> = 125 °C		1.2	-	
DC gate current not to trigger	I <sub>GD</sub>	T T	Maximum gate current/voltage not to trigger is the maximum value which will not trigger any unit with rated V <sub>DRM</sub> anode to cathode applied	) 10		mA
DC gate voltage not to trigger	V <sub>GD</sub>	$T_J = T_J \text{ maximum}$		0.:	25	V

THERMAL AND MECHANICAL SPECIFICATIONS						
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS		
Maximum operating junction temperature range	TJ	T <sub>J</sub>		°C		
Maximum storage temperature range	T <sub>Stg</sub>		-40 to 150			
Maximum thermal resistance, junction to case	R <sub>thJC</sub>	DC operation		K/W		
Maximum thermal resistance, case to heatsink	R <sub>thC-hs</sub>	Mounting surface, smooth, flat and greased	0.04			
Mounting torque + 10.0/		Non-lubricated threads	31 (275)	N⋅m		
Mounting torque, ± 10 %		Lubricated threads	24.5 (210)	(lbf · in)		
Approximate weight			280	g		
Case style		See dimensions - link at the end of datasheet	TO-93 (TO-209AB)			

△R <sub>thJC</sub> CONDUCTION						
CONDUCTION ANGLE	SINUSOIDAL CONDUCTION	RECTANGULAR CONDUCTION	TEST CONDITIONS	UNITS		
180°	0.016	0.012				
120°	0.019	0.020				
90°	0.025	0.027	$T_J = T_J$ maximum	K/W		
60°	0.036	0.037				
30°	0.060	0.060				

#### Note

• The table above shows the increment of thermal resistance RthJC when devices operate at different conduction angles than DC

Maximum Allowable Case Temperature (°C)

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## Vishay Semiconductors

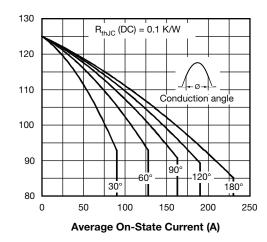


Fig. 1 - Current Ratings Characteristics

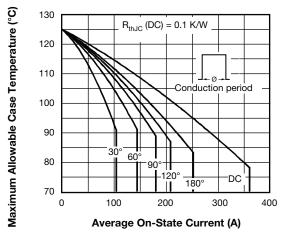


Fig. 2 - Current Ratings Characteristics

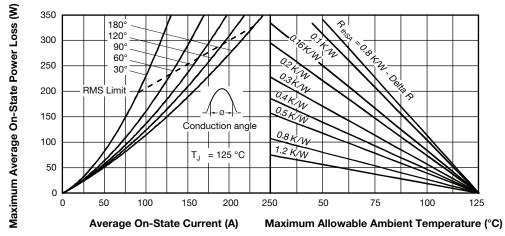


Fig. 3 - On-State Power Loss Characteristics

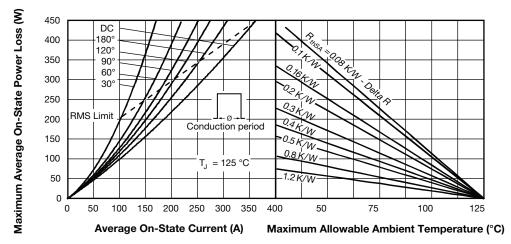


Fig. 4 - On-State Power Loss Characteristics

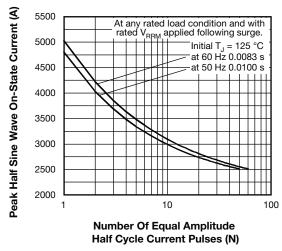


Fig. 5 - Maximum Non-Repetitive Surge Current

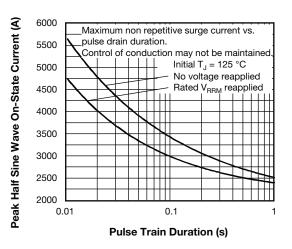


Fig. 6 - Maximum Non-Repetitive Surge Current

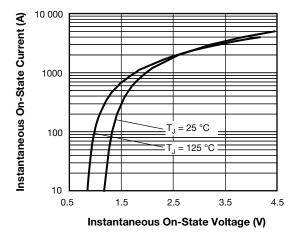


Fig. 7 - On-State Voltage Drop Characteristics

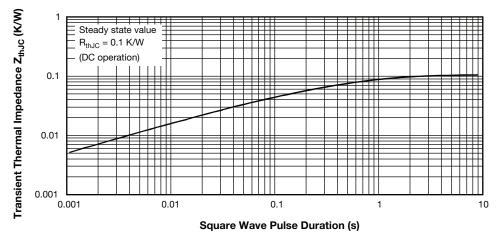


Fig. 8 - Thermal Impedance Z<sub>thJC</sub> Characteristics

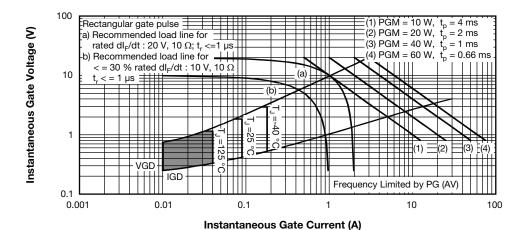
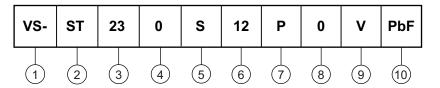


Fig. 9 - Gate Characteristics

#### **ORDERING INFORMATION TABLE**

Device code



Vishay Semiconductors product

**Thyristor** 

Essential part number

0 = converter grade

S = compression bonding stud

6 Voltage code x 100 = V<sub>RRM</sub> (see Voltage Ratings table)

P = stud base 3/4"-16UNF2A threads

0 = eyelet terminals (gate and auxiliary cathode leads)

1 = fast-on terminals (gate and auxiliary cathode leads)

9 V = glass-metal seal (only up to 1200 V)

10 None = standard production

PbF = lead (Pb)-free

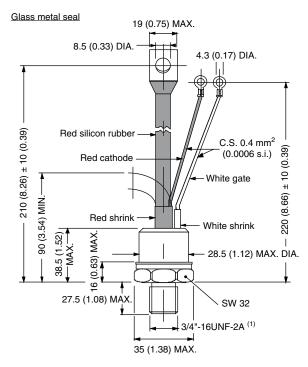
Note: For metric device M16 x 1.5 contact factory

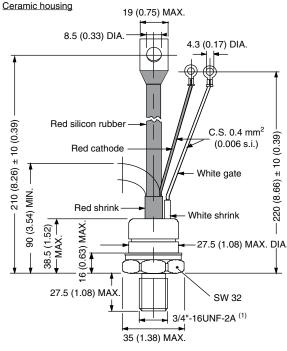
LINKS TO RELAT	ED DOCUMENTS
Dimensions	www.vishay.com/doc?95082

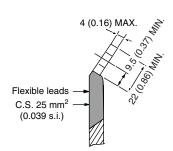


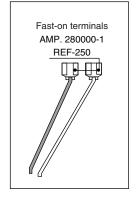
# TO-209AB (TO-93)

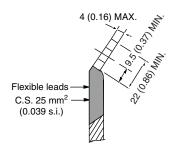
## **DIMENSIONS** in millimeters (inches)











#### Note

(1) For metric device: M16 x 1.5 - length 21 (0.83) maximum



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